

30V N-Channel Enhancement Mode MOSFET

Voltage

Current 42 A

DFN3333-8L

Features

• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@16A < 9m\Omega$

30 V

- R_{DS(ON)}, V_{GS}@4.5V,I_D@8A<13mΩ
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current	Tc=25°C	I _D	42	A	
	T _C =100°C		26		
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	168	<u> </u>	
Power Dissipation	T _C =25°C	PD	35		
	Tc=100°C		14	W	
Continuous Drain Current	T _A =25°C		10		
	T _A =70°C	Ι _D	8	A	
Power Dissipation	T _A =25°C		2.0	W	
Power Dissipation	T _A =70°C	Po	1.3		
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	٥C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R _{θJC}	3.6	•C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature



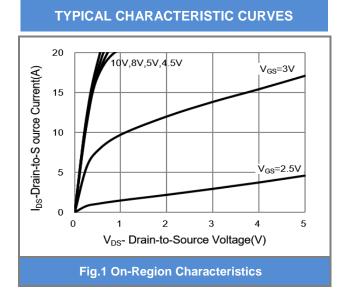
Electrical Characteristics (T_A=25°C unless otherwise noted)

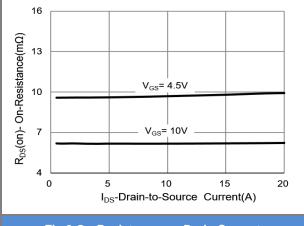
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	30	-	-	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250uA	1.0	1.7	2.5 V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =16A	-	6.2	9	mΩ
		V _{GS} =4.5V,I _D =8A	-	9.6	13	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =30V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Qg	V _{DS} =15V, I _D =20A, V _{GS} =4.5V ^(Note 2,3)	-	7.1	-	nC
Gate-Source Charge	Q _{gs}		-	3.1	-	
Gate-Drain Charge	Q _{gd}		-	2.0	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	763	-	pF
Output Capacitance	Coss		-	132	-	
Reverse Transfer Capacitance	Crss		-	81	-	
Turn-On Delay Time	td _(on)		-	5.4	-	ns
Turn-On Rise Time	tr	V _{DS} =15V, I _D =15A, V _{GS} =10V, R _G =6Ω	-	86	-	
Turn-Off Delay Time	td _(off)		-	20	-	
Turn-Off Fall Time	t _f	(14016 2,3)	-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is		-	-	42	А
Diode Forward Current Diode Forward Voltage	V _{SD}	Is=1A,V _{GS} =0V	-	0.7	1.0	V

NOTES :

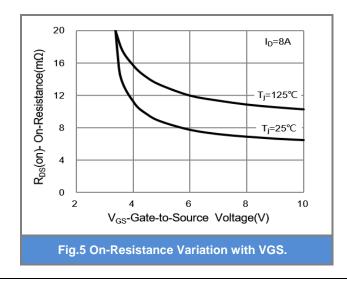
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.

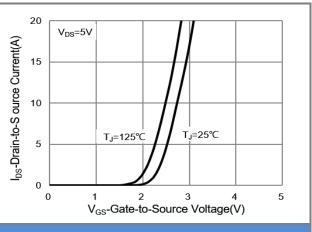




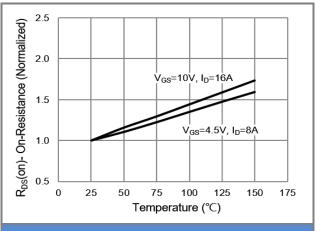




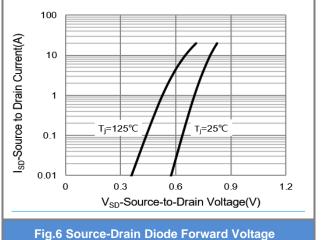




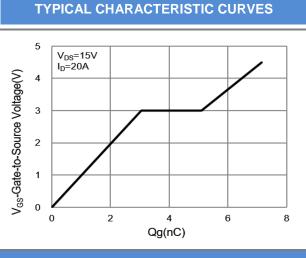














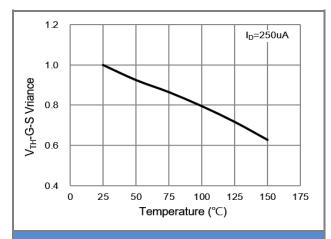
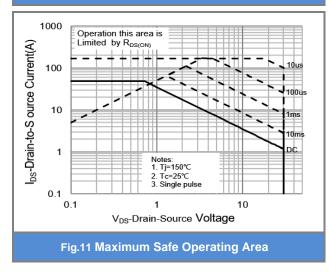
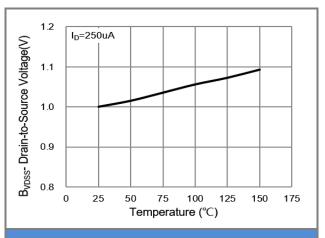


Fig.9 Threshold Voltage Variation with Temperature







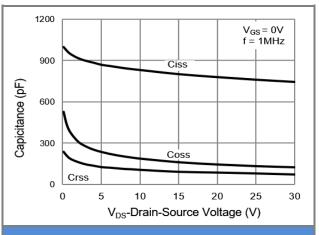
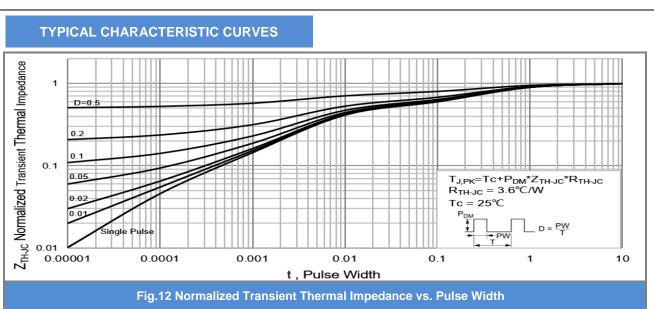


Fig.10 Capacitance vs. Drain-Source Voltage.



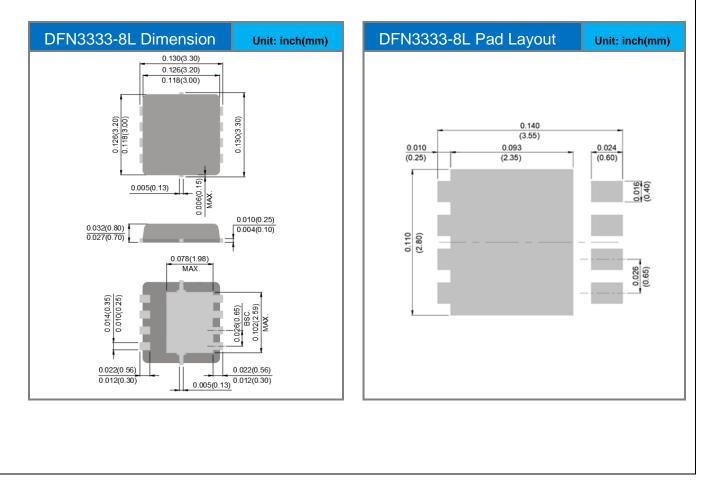




Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4408P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4408	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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